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Nota di contenuto	Front matter -- Contents -- Preface -- Introduction: Dark Passages -- 1. Toward Alphaville: Noir, Midcentury Communication, and the Management of Affect -- 2. Public Violence as Private Pathology: Noir Affect in The End of a Primitive -- 3. Cold Kink: Race and Sex in the African American Underworld -- 4. Noir Pedagogy: The Problem of Student Masochism in the Classroom Economy -- 5. The Shadows of the Twilight World: Beebo Brinker and the Circulation of Affect -- 6. Peripheral Noir, Mediation, and Capitalism: Noir Form, Noir Mediascape, Sociological Noir -- 7. Cyborg Affect and the Power of the Posthuman in the Ghost in the Shell Franchise -- 8. Playing with Negativity: Max Payne, Neoliberal Collapse, and the Noir Video Game -- 9. Chick Noir: Surveilling Femininity and the Affects of Loss in Gone Girl -- 10. Surplus Feelings: Neoliberal Noir and the Affective Economy of Debt -- 11. Capitalism as Affective Atmosphere: The Noir Worlds of Massimo Carlotto -- Afterword: Melodrama, Noir's Kid Sister, or Crying in Trump's America -- List of Contributors -- Index
Sommario/riassunto	Noir Affect proposes a new understanding of noir as defined by negative affect. This new understanding emphasizes that noir is, first and foremost, an affective disposition rather than a specific cycle of films or novels associated with a given time period or national tradition. Instead, the essays in Noir Affect trace noir's negativity as it manifests in different national contexts from the United States to

Mexico, France, and Japan and in a range of different media, including films, novels, video games, and manga. The forms of affect associated with noir are resolutely negative: These are narratives centered on loss, sadness, rage, shame, guilt, regret, anxiety, humiliation, resentment, resistance, and refusal. Moreover, noir often asks us to identify with those on the losing end of cultural narratives, especially the criminal, the lost, the compromised, the haunted, the unlucky, the cast-aside, and the erotically “perverse,” including those whose greatest erotic attachment is to death. Drawing on contemporary work in affect theory, while also re-orienting some of its core assumptions to address the resolutely negative affects narrated by noir, *Noir Affect* is invested in thinking through the material, bodily, social, and political-economic impact of the various forms noir affect takes. If much affect theory asks us to consider affect as a space of possibility and becoming, *Noir Affect* asks us to consider affect as also a site of repetition, dissolution, redundancy, unmaking, and decay. It also asks us to consider the way in which the affective dimensions of noir enable the staging of various forms of social antagonism, including those associated with racial, gendered, sexual, and economic inequality. Featuring an Afterword by the celebrated noir scholar Paula Rabinowitz and essays by an array of leading scholars, *Noir Affect* aims to fundamentally re-orient our understanding of noir. Contributors: Alexander Dunst, Sean Grattan, Peter Hitchcock, Justus Nieland, Andrew Pepper, Ignacio Sánchez Prado, Brian Rejack, Pamela Thoma, Kirin Wachter-Grene

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Autore	NASR, Zakariyya Ahmad
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Covers both the fundamentals and the state-of-the-art technology used for MBE. Written by expert researchers working on the frontlines of the field, this book covers fundamentals of Molecular Beam Epitaxy (MBE) technology and science, as well as state-of-the-art MBE technology for electronic and optoelectronic device applications. MBE applications to magnetic semiconductor materials are also included for future magnetic and spintronic device applications. Molecular Beam Epitaxy: Materials and Applications for Electronics and Optoelectronics is presented in five parts: Fundamentals of MBE; MBE technology for electronic devices application; MBE for optoelectronic devices; Magnetic semiconductors and spintronics devices; and Challenge of MBE to new materials and new researches. The book offers chapters covering the history of MBE; principles of MBE and fundamental mechanism of MBE growth; migration enhanced epitaxy and its application; quantum dot formation and selective area growth by MBE; MBE of III-nitride semiconductors for electronic devices; MBE for Tunnel-FETs; applications of III-V semiconductor quantum dots in optoelectronic devices; MBE of III-V and III-nitride heterostructures for optoelectronic devices with emission wavelengths from THz to ultraviolet; MBE of III-V semiconductors for mid-infrared photodetectors and solar cells; dilute magnetic semiconductor materials and ferromagnet/semiconductor heterostructures and their application to spintronic devices; applications of bismuth-containing III-V semiconductors in devices; MBE growth and device applications of Ga₂O₃; Heterovalent semiconductor structures and their device applications; and more. Includes chapters on the fundamentals of MBE. Covers new challenging researches in MBE and new technologies. Edited by two pioneers in the field of MBE with contributions from well-known MBE authors including three AI Cho MBE Award winners. Part of the Materials for Electronic and Optoelectronic Applications series. Molecular Beam Epitaxy: Materials and Applications for Electronics and Optoelectronics will appeal to graduate students, researchers in academia and industry, and others interested in the area of epitaxial growth.
